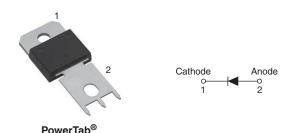
VS-85EPF12 Soft Recovery Series

Vishay Semiconductors

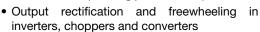
Fast Soft Recovery Rectifier Diode, 85 A



PRIMARY CHARACTERISTICS				
I _{F(AV)}	85 A			
V_{R}	1200 V			
V _F at I _F	1.36 V			
I _{FSM}	1250 A			
t _{rr}	95 ns			
T _J max.	150 °C			
Snap factor	0.5			
Package	PowerTab [®]			
Circuit configuration	Single			

FEATURES

- · Glass passivated pellet chip junction
- 150 °C max. operating junction temperature





- Input rectifications where severe restrictions on conducted EMI should be met
 - ns Rol

- Screw mounting only
- Designed and qualified according to JEDEC®-JESD 47
- AEC-Q101 qualified
- PowerTab® package
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION

The VS-85EPF12 fast soft recovery rectifier series has been optimized for combined short reverse recovery time and low forward voltage drop.

The glass passivation ensures stable reliable operation in the most severe temperature and power cycling conditions. Available in the new PowerTab package, this new series is suitable for a large range of applications combining excellent die to footprint ratio and sturdiness connectivity for use in high current environments.

MAJOR RATINGS AND CHARACTERISTICS				
SYMBOL	CHARACTERISTICS	VALUES	UNITS	
I _{F(AV)}	Rect. conduction 50 % duty cycle at T _C = 85 °C	85	Λ	
I _{F(RMS)}		160	Α Α	
V _{RRM}		1200	V	
I _{FSM}		1250	Α	
V _F	100 A, T _J = 25 °C	1.4	V	
t _{rr}	1 A, - 100 A/μs	95	ns	
T _J	Range	-40 to +150	°C	

VOLTAGE RATINGS			
TYPE NUMBER	V _{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} AT 150 °C mA
VS-85EPF12	1200	1300	15

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL TEST CONDITIONS VALUES		VALUES	UNITS	
Maximum average forward current	I _{F(AV)}	T _C = 85 °C, 180° conduction half sine wave	85		
Maximum peak one cycle non-repetitive surge current	I _{FSM}	10 ms sine pulse, rated V _{RRM} applied	1100	А	
		10 ms sine pulse, no voltage reapplied	1250		
Maximum I ² t for fusing	l ² t	10 ms sine pulse, rated V _{RRM} applied		5000	A ² s
		10 ms sine pulse, no voltage reapplied	7000	A-S	
Maximum I ² √t for fusing	I ² √t	t = 0.1 ms to 10 ms, no voltage reapplied	70 000	A ² √s	

VS-85EPF12 Soft Recovery Series

Vishay Semiconductors

ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum forward voltage drop	V_{FM}	85 A, T _J = 25 °C		1.36	V
Forward slope resistance	r _t	- T _J = 150 °C		4.03	mΩ
Threshold voltage	V _{F(TO)}			0.87	V
Maximum reverse leakage current	I _{RM}	T _J = 25 °C	V _R = Rated V _{RRM}	0.1	mA
Maximum reverse leakage current		T _J = 150 °C		15	IIIA

RECOVERY CHARACTERISTICS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	· •
Reverse recovery time	t _{rr}	l⊏ at 85 A _{ak}	480	ns	I _{FM} t
Reverse recovery current	I _{rr}	. I _F at 85 A _{pk} 25 Α/μs : 25 °C	7.1	А	
Reverse recovery charge	Q _{rr}		2.1	μC	dir/ Q
Snap factor	S		0.5		I _{RM(REC)}

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and st temperature range	orage	T _J , T _{Stg}		-40 to +150	°C
Maximum thermal resista junction to case	nce,	R _{thJC}	DC operation	0.35	
Maximum thermal resista junction to ambient	nce,	R _{thJA}		40	°C/W
Typical thermal resistance case to heatsink	э,	R _{thCS}	Mounting surface, smooth and greased	0.2	
Approximate weight				6	g
Approximate weight				0.21	OZ.
Mounting torque	minimum			6 (5)	kgf · cm
	maximum			12 (10)	(lbf ⋅ in)
Marking device			Case style PowerTab®	85EPF12	



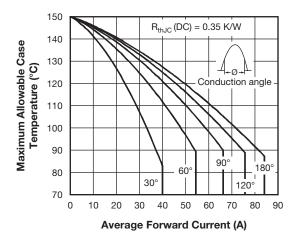


Fig. 1 - Current Rating Characteristics

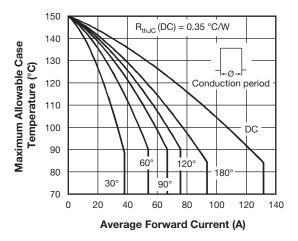


Fig. 2 - Current Rating Characteristics

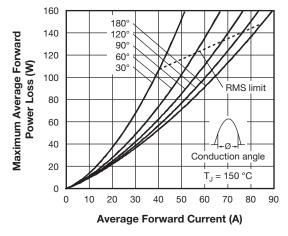


Fig. 3 - Forward Power Loss Characteristics

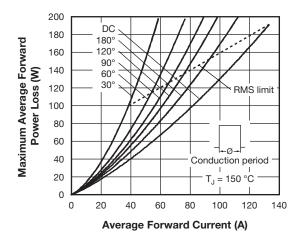


Fig. 4 - Forward Power Loss Characteristics

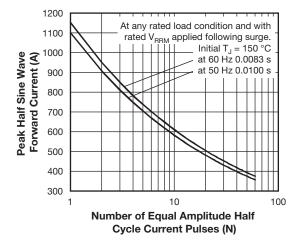


Fig. 5 - Maximum Non-Repetitive Surge Current

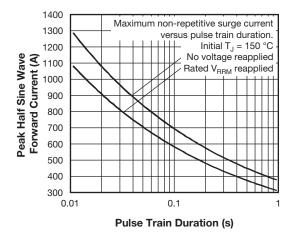
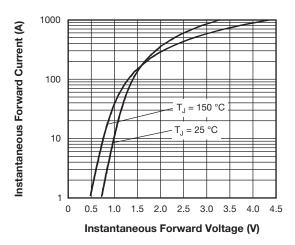


Fig. 6 - Maximum Non-Repetitive Surge Current



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Fig. 7 - Forward Voltage Drop Characteristics

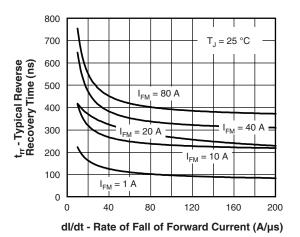


Fig. 8 - Recovery Time Characteristics, T_J = 25 °C

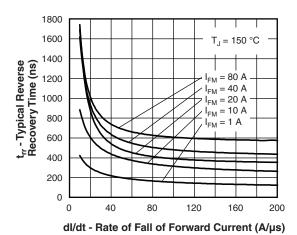


Fig. 9 - Recovery Time Characteristics, $T_J = 150~^{\circ}\text{C}$

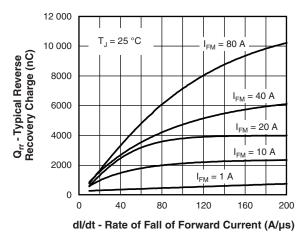


Fig. 10 - Recovery Charge Characteristics, $T_J = 25$ °C

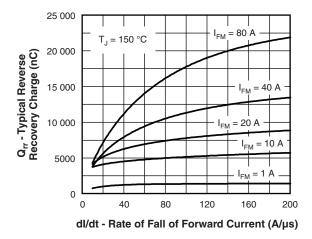


Fig. 11 - Recovery Charge Characteristics, T_J = 150 °C

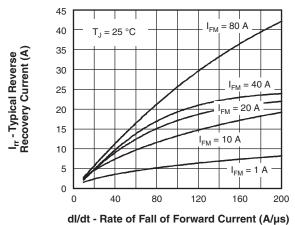


Fig. 12 - Recovery Current Characteristics, $T_J = 25$ °C

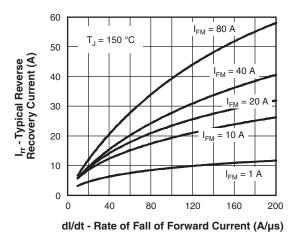


Fig. 13 - Recovery Current Characteristics, T_J = 150 °C

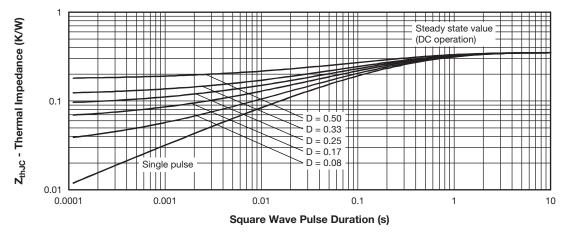


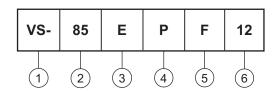
Fig. 14 - Thermal Impedance Z_{thJC} Characteristics

VS-85EPF12 Soft Recovery Series

Vishay Semiconductors

ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Current rating

3 - Circuit configuration:

E = Single diode

4 - Package:

P = TO-247AC

5 - Type of silicon:

F = Fast recovery

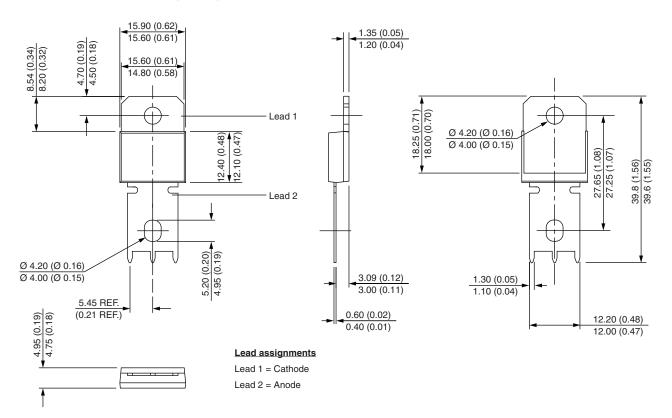
6 - Voltage code x 100 = V_{RRM} (12 = 1200 V)

LINKS TO RELATED DOCUMENTS				
Dimensions <u>www.vishay.com/doc?95240</u>				
Part marking information	www.vishay.com/doc?95370			
Application note	www.vishay.com/doc?95179			



PowerTab[®]

DIMENSIONS in millimeters (inches)





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